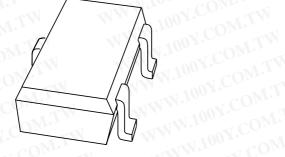
DISCRETE SEMICONDUCTORS





WW.100Y.COM.TV W.100Y.COM.TV BC856W; BC857W; BC858W PNP general purpose transistors

Product data sheet Supersedes data of 1999 Apr 12 2002 Feb 04

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FEATURES

- Low current (max. 100 mA)
- Low voltage (max. 65 V).

APPLICATIONS

• General purpose switching and amplification.

DESCRIPTION

PNP transistor in a SOT323 plastic package. NPN complements: BC846W, BC847W and BC848W.

MARKING

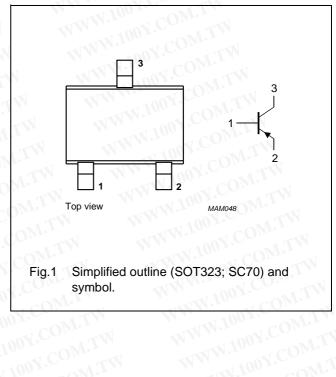
TYPE NUMBER	MARKING CODE ⁽¹⁾			
BC856W	3D*			
BC856AW	3A*			
BC856BW	3B*			
BC857W	3H*			
C857AW 3E*				
BC857BW	3F*			
BC857CW 3G*				
BC858W 3M*				

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BC856W; BC857W; **BC858W**

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



Note

- 1. * = -: made in Hong Kong.
 - * = t: made in Malaysia. WWW.100Y.COM.

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SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT	
V _{CBO}	collector-base voltage	open emitter	COMMIN	V		
	BC856W	WW.100	COM-1	-80	V	
	BC857W	TW W 100	Mo	-50	V	
	BC858W	TW WWW.10	0X-ON	-30	V	
V _{CEO}	collector-emitter voltage	open base	008.00	IN		
	BC856W	TW WWW.	IN SI COM	-65	V	
	BC857W	MWW WWW	TO VO	-45	V	
1001.COM	BC858W	WWW WWW	V.100 - CC	-30	V	
V _{EBO}	emitter-base voltage	open collector	WILLON C	-5	V	
Ic of Y	collector current (DC)	T.M.	-100x.	-100	mA	
СМ	peak collector current	W WILL	- 100Y	-200	mA	
BM	peak base current	W WT. MONY	W	-200	mA	
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	NNEW. PO	200	mW	
T _{stg}	storage temperature	COM.1	-65	+150	°C	
Тј 100	junction temperature	00 L. ONLIN	1.W.	150	°C	
T _{amb}	operating ambient temperature	10 Y.C. M.TW	-65	+150	°C	

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	in free air; note 1	625	K/W

Note

1. Refer to SOT323 standard mounting conditions. WWW.100Y. WWW.100Y.COM.T

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PNP general purpose transistors

BC856W; BC857W; BC858W

CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = -30 \text{ V}; I_E = 0$	<u>O</u> M	-1	-15	nA
	WWW.100X.COM.IT	$V_{CB} = -30 \text{ V}; I_E = 0;$ T _j = 150 °C	COM	TW	-4	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_{C} = 0$	-	NT.	-100	nA
h _{FE} COM 001.COM 1001.COM 1001.COM	DC current gain BC856W BC857W; BC858W BC856AW; BC857AW BC856BW; BC857BW BC857CW	$I_{C} = -2 \text{ mA}; V_{CE} = -5 \text{ V}$	125 125 125 220 420	N.TN M.TV OM.T COM	475 800 250 475 800	
V _{CEsat}	collector-emitter saturation voltage	$I_{\rm C} = -10 \text{ mA}; I_{\rm B} = -0.5 \text{ mA}$		-75	-300	mV
WW.1001.C	OMAT WWW.100Y	$I_{\rm C} = -100 \text{ mA}; I_{\rm B} = -5 \text{ mA};$ note 1	N.10	-250	-600	mV
V _{BEsat}	base-emitter saturation voltage	$I_{\rm C} = -10$ mA; $I_{\rm B} = -0.5$ mA		-700	T.M.T	mV
	COMTW WWW.10	$I_{C} = -100 \text{ mA}; I_{B} = -5 \text{ mA};$ note 1	NMM.	-850	coM. ¹	mV
V _{BE}	base-emitter voltage	$I_{C} = -2 \text{ mA}; V_{CE} = -5 \text{ V}$	-600	-650	-750	mV
WWW I	WITH WITH	$I_{C} = -10 \text{ mA}; V_{CE} = -5 \text{ V}$	-	14.100	-820	mV
Cc	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB} = -10 \ \text{V}; \ \textbf{I}_{E} = \textbf{I}_{e} = 0; \\ \textbf{f} = 1 \ \text{MHz} \end{array}$	-41	N.100	3	pF
Ce	emitter capacitance	$\label{eq:VEB} \begin{array}{l} V_{EB} = -0.5 \; V; \; I_{C} = I_{c} = 0; \\ f = 1 \; MHz \end{array}$	- 1	H W.	12	pF
f _T	transition frequency	$V_{CE} = -5 \text{ V}; I_C = -10 \text{ mA};$ f = 100 MHz	100	NWW -	7001.	MHz
F	noise figure	$ I_C = -200 \ \mu\text{A}; \ V_{CE} = -5 \ V; \\ R_S = 2 \ k\Omega; \ f = 1 \ k\text{Hz}; \\ B = 200 \ \text{Hz} $	-	MM	10	dB

Note

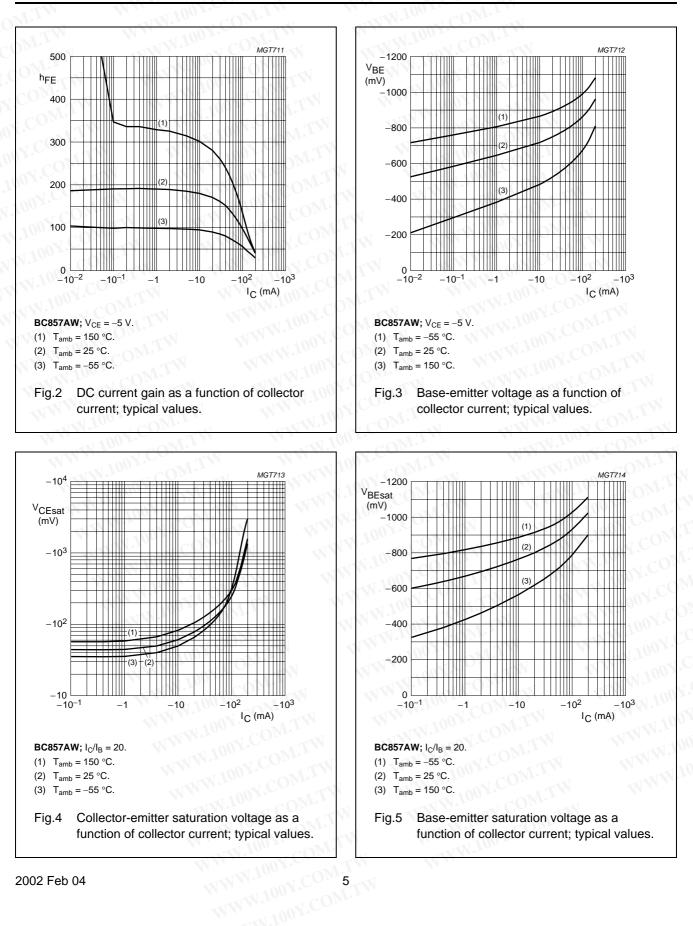
1. Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02.$ WWW.100Y.COM.TW

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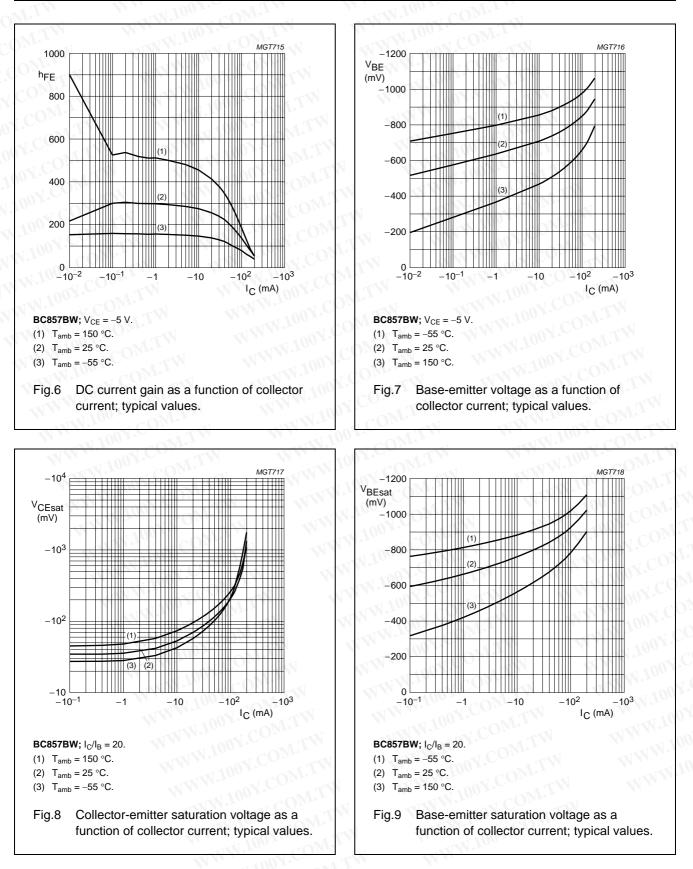
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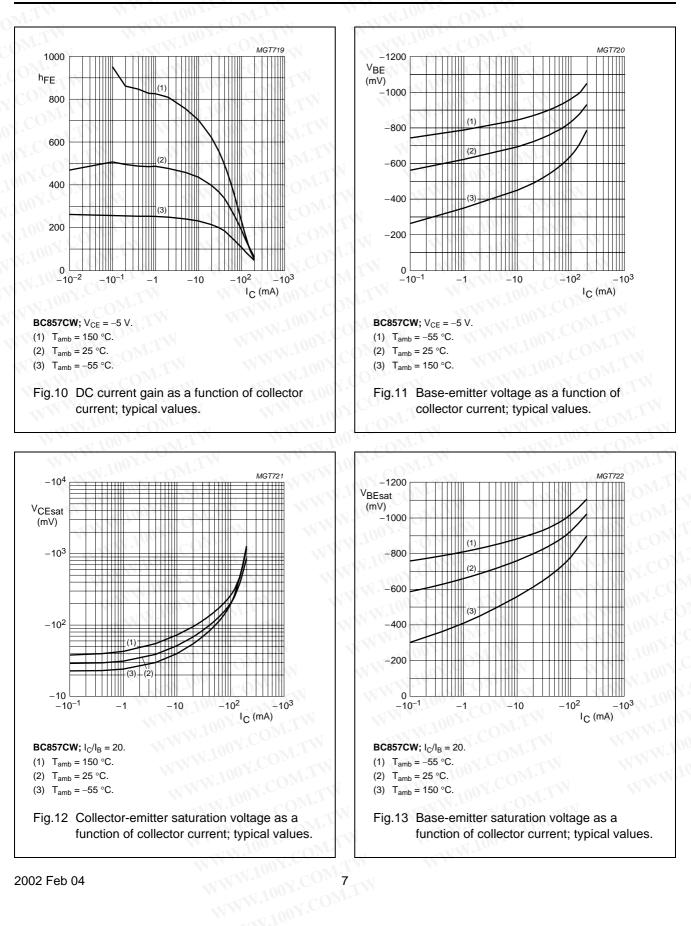
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BC856W; BC857W; BC858W



BC856W; BC857W; BC858W

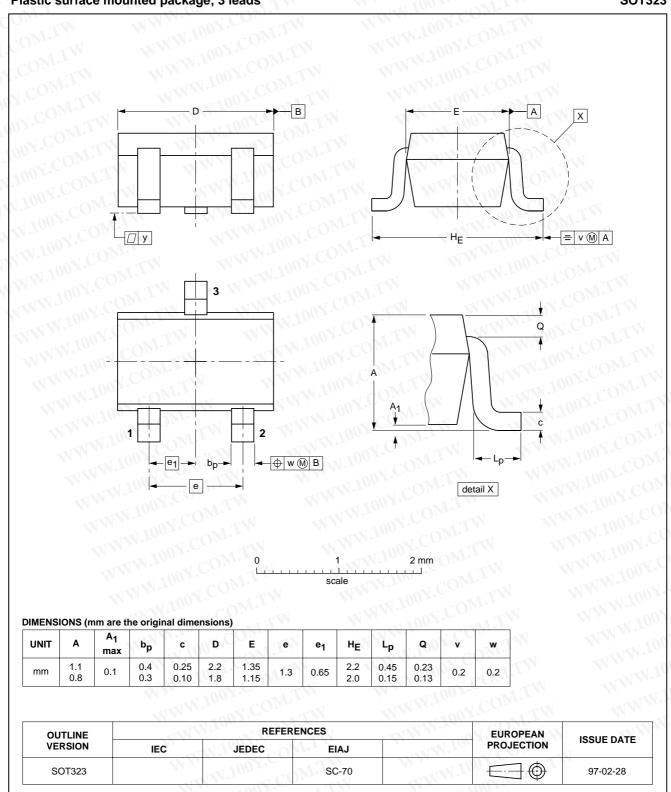


BC856W; BC857W; BC858W

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads





BC856W; BC857W; BC858W

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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